# QM/MM approaches in *ab initio* molecular dynamics

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### Outline

- Overview of the QM/MM methodology
- Available QM/MM Electrostatic
   Schemes
- GEEP: CP2K QM/MM driver
- Charged Oxygen Vacancies in SiO2

# Nobel Prize in Chemistry 2013

Martin Karplus, Harvard U., Cambridge, MA, USA Micheal Levitt, Stanford U., Stanford, CA, USA Arieh Warshel, U. Southern Ca., Los Angeles, CA, USA **Development of Multiscale Models of Complex Chemical Systems** 

### Combine QM and MM



#### full atomistic by classical FF



 $V(\mathbf{R}) = V_{\rm QM}(\mathbf{R}) + V_{\rm MM}(\mathbf{R}) + V_{\rm int}(\mathbf{R})$ 

# QMMM: overview



P.D. Blood and G.A. Voth, *PNAS*, 103, **2006**, pp. 15068-15072

# QMMM: overview



QMMM:overview

#### QMMM: overview

0.11 million atoms 5 QM regions: effects of O implantation into Si adaptive QM regions



#### simoX technology

Yoshio Tanaka (AIST) and Aiichiro Nakano (USC)

# QMMM: overview



$$E_{QM/MM} = \int d\vec{r} \rho_{tot}^{QM}(\vec{r}) \cdot V^{MM}(\vec{r})$$

Computing  $V^{MM}(\vec{r})$  on the same cell on which is defined  $\rho_{tot}^{QM}(\vec{r})$ 

T. Laino et al, J. Chem. Theory Comput., 1, 2005, pp. 1176-1184 T. Laino et al, J. Chem. Theory Comput., 2, 2006, pp. 1370-1378

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# Available QM/MM Electrostatic Schemes

 $Cost \approx N_{MM} * P^1$ 



GEEP

Application: cOVD

# Available QM/MM Electrostatic Schemes

Spherical Cutoff Cost  $\approx N_{MM}^{c} * P^{1}$ 



# Available QM/MM Electrostatic Schemes



A. Laio, J. VandeVondele, U. Rothlisberger , J. Chem. Phys., 116, 2002, pp. 6941

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# QM/MM



#### Gaussian charge distribution

$$n(\mathbf{r}, \mathbf{R}_{\mathrm{MM}}) = \left(\frac{r_{c,\mathrm{MM}}}{\sqrt{\pi}}\right)^3 e^{-(|\mathbf{r}-\mathbf{R}_{\mathrm{MM}}|/r_{c,\mathrm{MM}})^2}$$

$$v_{\mathrm{MM}}(\mathbf{r}, \mathbf{R}_{\mathrm{MM}}) = rac{\mathrm{Erf}\left(rac{|\mathbf{r} - \mathbf{R}_{\mathrm{MM}}|}{r_{c,\mathrm{MM}}}
ight)}{|\mathbf{r} - \mathbf{R}_{\mathrm{MM}}|}$$

#### prevent spill out problem accelerate calculations of electrostatics

GEEP

$$\frac{\operatorname{Erf}(\frac{r}{r_c})}{r} = \sum_{N_g} A_g \, \exp^{-\left(\frac{r}{G_g}\right)^2} + R_{low}(r)$$

$$rac{\mathrm{Erf}(rac{r}{r_c})}{r}$$



T. Laino, F. Mohamed, A. Laio and M. Parrinello, J. Chem. Th. Comp., 1, 2005, pp. 1176-1184

### Multigrid Framework

$$\frac{\operatorname{Erf}(\frac{r}{r_c})}{r} = \sum_{N_g} A_g \, \exp^{-\left(\frac{r}{G_g}\right)^2} + R_{low}(r)$$



#### Collocation in the QM Box

 $E_{\rm QM/MM}(\mathbf{R}_{\rm QM}, \mathbf{R}_{\rm MM}) = \int n(\mathbf{r}, \mathbf{R}_{\rm QM}) V^{\rm QM/MM}(\mathbf{r}, \mathbf{R}_{\rm MM}) d\mathbf{r}$ 

potential on the finest QM grid













#### compact Gaussian functions













Scaling ~  $Nc^3$ 





( )



( )

#### **Electrostatic Potential**



#### &QMMM

&CELL ABC 6.0 6.0 6.0 &END CELL USE\_GEEP\_LIB 9 ECOUPL GAUSS

&MM\_KIND H RADIUS 0.44 &END MM\_KIND &MM\_KIND 0 RADIUS 0.78 &END MM\_KIND

&QM\_KIND H MM\_INDEX 8 9 &END QM\_KIND &QM\_KIND 0 MM\_INDEX 7 &END QM\_KIND

&END QMMM

# Extension to PBC

How to handle the electrostatic potential in presence of periodic boundary conditions (PBC)?

Ewald Summation scheme:

$$V(\vec{r}) = \sum_{MM} q_{MM} \frac{1}{|\vec{r} - \vec{r}_{MM}|}_{\vec{k} \cdot \vec{r}}$$

$$V_{rec}(\vec{r}) = \frac{4\pi}{\Omega} \sum_{\vec{k} \neq \pm} \sum_{MM} q_{MM} \frac{1}{|\vec{r} - \vec{r}_{MM}|}_{q_{MM}} \text{Reciprocal space}$$

$$V_{real}(\vec{r}) = \sum_{MM} \sum_{\vec{n}} V_{rec}(\vec{r}) \frac{1}{|\vec{r} + \vec{n}|} \frac{V_{real}(\vec{r}) + \vec{n}|}{|\vec{r} - \vec{r}_{MM}|}$$
Real space

### QM/MM fully periodic



### Total ES Energy

$$n(\mathbf{r}) = n^{\text{QM}}(\mathbf{r}) + n^{\text{MM}}(\mathbf{r}) \pm n^{B}$$
  
background charge

$$E^{\text{TOT}} = \frac{1}{2} \int \int d\mathbf{r} d\mathbf{r}' \frac{n(\mathbf{r})n(\mathbf{r}')}{|\mathbf{r} - \mathbf{r}'|}$$

$$E^{\mathrm{MM}} = \frac{1}{2} \int \int d\mathbf{r} d\mathbf{r}' \frac{(n^{\mathrm{MM}}(\mathbf{r}) + n^{B,\mathrm{MM}})(n^{\mathrm{MM}}(\mathbf{r}') + n^{B,\mathrm{MM}})}{|\mathbf{r} - \mathbf{r}'|}$$
$$E^{\mathrm{QM}} = \frac{1}{2} \int \int d\mathbf{r} d\mathbf{r}' \frac{(n^{\mathrm{QM}}(\mathbf{r}) + n^{B,\mathrm{QM}})(n^{\mathrm{QM}}(\mathbf{r}') + n^{B,\mathrm{QM}})}{|\mathbf{r} - \mathbf{r}'|}$$

$$E^{\mathrm{QM/MM}} = \int \int d\mathbf{r} d\mathbf{r}' \frac{(n^{\mathrm{QM}}(\mathbf{r}) + n^{B,\mathrm{QM}})(n^{\mathrm{MM}}(\mathbf{r}') + n^{B,\mathrm{MM}})}{|\mathbf{r} - \mathbf{r}'|}$$

### MM/MM fully periodic



### QM/MM fully periodic



### GEEP with PBC

$$\frac{\operatorname{Erf}(\frac{r}{r_c})}{r} = \sum_{N_g} A_g \, \exp^{-\left(\frac{r}{G_g}\right)^2} + R_{low}(r)$$

$$V(r)_{real} = \sum_{N_g} A_g \, \exp^{-\left(\frac{r}{G_g}\right)^2}$$



#### QM/MM real space term



QM/MM reciprocal space term

$$V(r)_{rec} = \frac{1}{\Omega} \sum_{k}^{k_{cut}} \tilde{R}_{low}(k) e^{i\vec{k}\cdot\vec{r}}$$

$$\tilde{R}_{low}(k) = \begin{bmatrix} \frac{4\pi}{|\vec{k}|^2} \end{bmatrix} e^{-\frac{|\vec{k}|^2 r_c^2}{4}} - \sum_{N_g} A_g(\pi)^{\frac{3}{2}} G_g^3 e^{-\frac{|\vec{k}|^2 G_g^2}{4}}$$

low cutoff function only few k vectors needed

&QMMM

&CELL ABC 17.320500 17.320500 17.320500 &END CELL

ECOUPL GAUSS USE\_GEEP\_LIB 6

&MM\_KIND NA RADIUS 1.5875316249000 &END MM\_KIND &MM\_KIND CL RADIUS 1.5875316249000 &END MM\_KIND

&PERIODIC GMAX 0.5 &MULTIPOLE EWALD\_PRECISION 0.00000001 RCUT 8.0 ANALYTICAL\_GTERM &END MULTIPOLE &END PERIODIC

&END QMMM

# GEEP Summary

- GEEP is a technique to speed up the evaluation of a function on a grid
- The speed up factor is ~  $(Nf/Nc)^3 = 2^{3(Ngrid-1)}$
- Usually 3-4 grid levels are used corresponding to a speed up of 64-512 ~ 10<sup>2</sup> times faster than the simple collocation algorithm (Interpolations and Restrictions account for a negligible amount of time)

# GEEP Summary

Since the residual function is different from zero only for few k vectors, the sum in reciprocal space is restrained to few points.

Small computational overhead between the fully periodic and non-periodic

# Sources of Errors

- Cutoff of grid level appropriate to the cutoff of the mapped Gaussian (~ 20-25 points per linear direction)
- Error in Cubic Spline interpolation
- Cutoff of the coarse grid level comparable to the cutoff of the long range function.

### QM fully periodic



### QM fully periodic



### De-coupling and re-coupling



### Bloechl Scheme

Density fitting in g-space of the total density

$$\hat{m}(\mathbf{r}, \mathbf{R}_{\text{QM}}) = \sum_{\text{QM}} q_{\text{QM}} g_{\text{QM}}(\mathbf{r}, \mathbf{R}_{\text{QM}})$$

• Reproduce the correct Long-Range electrostatics  $\Delta Q_{l} = \left| \int d\mathbf{r} \, \mathbf{r}^{l} \mathcal{Y}_{l} \left( n(\mathbf{r}, \mathbf{R}_{QM}) - \hat{n}(\mathbf{r}, \mathbf{R}_{QM}) \right) \right|$   $\Delta W = \left| \int d\mathbf{r} \, \mathbf{r}^{2} \left( n(\mathbf{r}, \mathbf{R}_{QM}) - \hat{n}(\mathbf{r}, \mathbf{R}_{QM}) \right) \right|$ minimise

#### Decoupling and Recoupling using these charges

P. E. Bloechl, J. Chem. Phys., 103 (17), 1995, pp.7422-7428
T. Laino, F. Mohamed, A. Laio and M. Parrinello, J. Chem. Th. Comp., 2 (5), 2006, pp.1370-1378

### Charged OV

#### Migration of charged oxygen vacancy defects in silica



dimer deloc. el.





E<sub>1</sub>\*

T. Laino, D. Donadio, I-Feng W. Kuo, Phys. Rev. B, 2007



### NEB: Minimum Energy Path





T. Laino, D. Donadio, I-Feng W. Kuo, Phys. Rev. B, 2007

#### Image Charge & QMMM

#### QM molecule + EAM metal

nitrobenzene/Au(111)



$$\rho_{\rm IC}(\mathbf{r}) = \sum_{I_{\rm met}} C_{I_{\rm met}} \exp\left[-\alpha |\mathbf{r} - \mathbf{R}_{I_{\rm met}}|^2\right]$$

$$V_H(\mathbf{r}) + V_{\rm IC}(\mathbf{r}) = \int \frac{\rho(\mathbf{r}') + \rho_{\rm IC}(\mathbf{r}')}{|\mathbf{r} - \mathbf{r}'|} d\mathbf{r}' = V_0$$

IC induce polarization, solved selfconsistently

Siepmann Sprik., JCP (1995) **102** Golze Iannuzzi Passerone Hutter, JCTC (2013)





#### IC distribution



$$\int \left(V_H(\mathbf{r}) + V_{\rm IC}(\mathbf{r}) - V_0\right) g_I(\mathbf{r}) = \int \left(V_H(\mathbf{r}) - V_0\right) g_I(\mathbf{r}) + \sum_J C_J \int \int \frac{g_J(\mathbf{r}')g_I(\mathbf{r})}{|\mathbf{r} - \mathbf{r}'|} d\mathbf{r} d\mathbf{r}'$$

linear set of eq. (CG iterative scheme)



#### H<sub>2</sub>O cluster on Pt(111)

#### H<sub>2</sub>O QM, Pt EAM, H<sub>2</sub>O-Pt Siepmann-Sprik + IC



	1 H <sub>2</sub> O		$2H_2O$			12H <sub>2</sub> O		
kJ/mol	E <sub>int</sub>	Eads	E <sub>int</sub>	Eads	E <sub>H-bond</sub>	E <sub>int</sub>	Eads	E <sub>H-bond</sub>
QM/MM	-41.6	-37.3	-40.9	-49.2	-10.6	-36.4	-61.9	-26.0
IC-QM/MM	-44.2	-43.6	-43.7	-52.9	-10.5	-42.8	-66.6	-24.4
full DFT	-44.9	-43.5	-50.6	-56.8	-7.0	-44.2	-63.0	-19.7

#### Liquid Water at Pt(111)





honeycomb arrangement 70% on-top site occupied



#### H-bond distribution

